



Product data sheet

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If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or phone (details via salesaddresses@nxp.com). Thank you for your cooperation and understanding,

NXP Semiconductors



FEATURES

- Low diode capacitance
- Low diode forward resistance.

APPLICATIONS

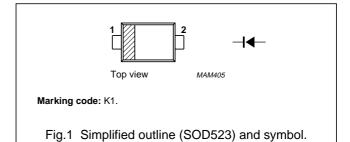
• General RF applications.

DESCRIPTION

General purpose PIN diode in a SOD523 ultra small SMD plastic package.

PINNING

PIN	DESCRIPTION	
1	cathode	
2	anode	



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _R	continuous reverse voltage		-	60	V
IF	continuous forward current		-	50	mA
P _{tot}	total power dissipation	T _s = 90 °C	-	715	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

ELECTRICAL CHARACTERISTICS

 $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	forward voltage	I _F = 50 mA	-	0.95	1.1	V
V _R	reverse voltage	I _R = 10 μA	50	-	-	V
I _R	reverse current	V _R = 50 V	-	-	100	nA
C _d	diode capacitance	V _R = 0; f = 1 MHz	-	0.4	-	pF
		V _R = 1 V; f = 1 MHz	-	0.3	0.55	pF
		V _R = 5 V; f = 1 MHz	-	0.2	0.35	pF
r _D	diode forward resistance	I _F = 0.5 mA; f = 100 MHz; note 1	-	5.5	9	Ω
		I _F = 1 mA; f = 100 MHz; note 1	-	3.6	6.5	Ω
		I _F = 10 mA; f = 100 MHz; note 1	-	1.5	2.5	Ω

Note

1. Guaranteed on AQL basis: inspection level S4, AQL 1.0.

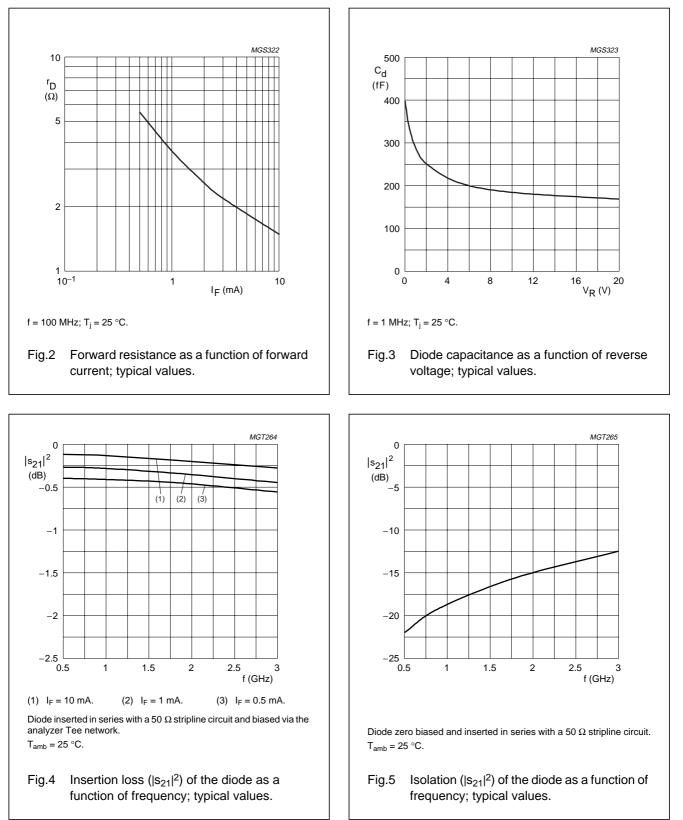
THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th j-s}	thermal resistance from junction to soldering point		K/W

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GRAPHICAL DATA

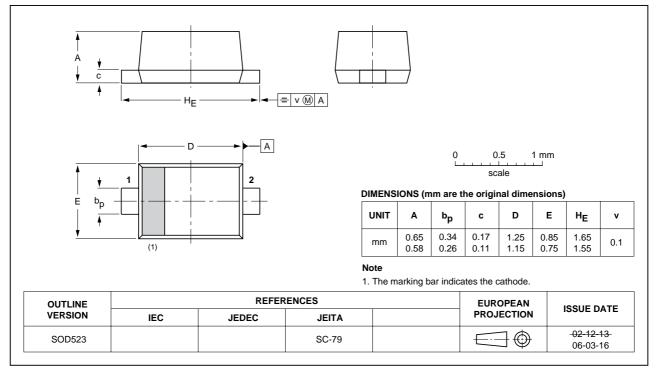


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SOD523

PACKAGE OUTLINE

Plastic surface-mounted package; 2 leads



Legal information

Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Revision history

Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
BAP51-02_N_3	20080102	Product data sheet	-	BAP51-02_2	
Modifications: • Package outline drawing on page 4 changed					
BAP51-02_2 (9397 750 07151)	20000706	Product specification	-	BAP51-02_N_1	
BAP51-02_N_1 (9397 750 06152)	19990628	Preliminary specification	-	-	

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Date of release: 2 January 2008 Document identifier: BAP51-02_N_3